



## DIODE MODULES

M4.1, M4.1A, M4.1B, M4.1C, M4.1G

25A, 40A, 63A, 80A, 100A, 125A, 160A, 200A, 250A; 12 class

## DATASHEET IN BRIEF

A module of single diode is intended for using composed of power converters.

## OVERALL DRAWINGS

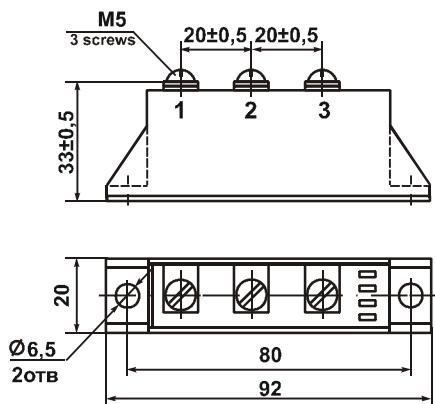


Figure 1 – Overall drawing of housing E1  
M4.1, M4.1A; M4.1B, M4.1C, M4.1D – for currents: 25 A – 80 A

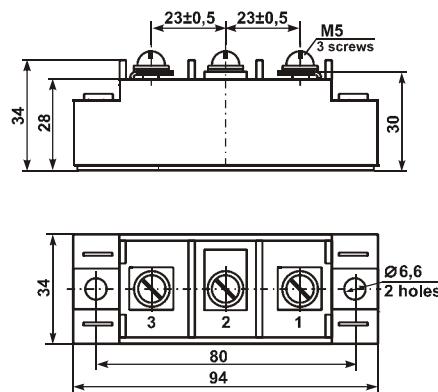


Figure 2 – Overall drawing of housing E2  
M4.1, M4.1A; M4.1B, M4.1C, M4.1D – for currents: 25A – 160 A

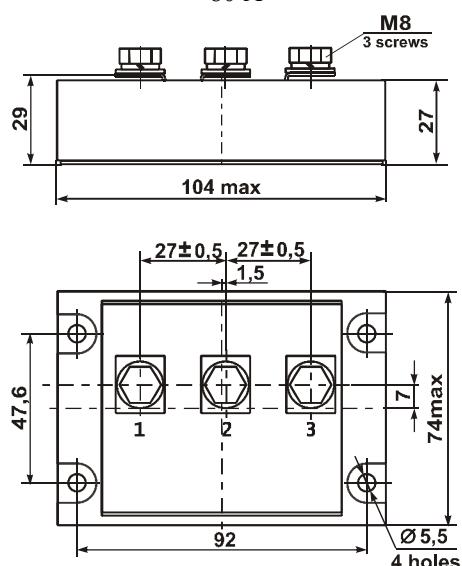


Figure 3 – Overall drawing of housing DM  
M4.1, M4.1A; M4.1B, M4.1C, M4.1D – for currents: 200 A

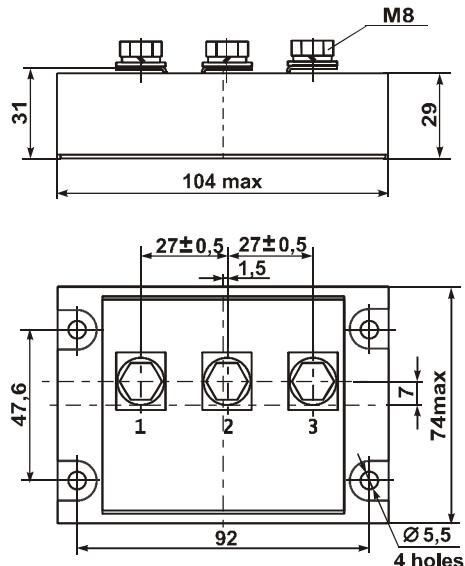


Figure 4 – Overall drawing of housing DM  
M4.1, M4.1A; M4.1B, M4.1C, M4.1D – for currents: 250 A

## INTERNAL CONNECTION CIRCUITS

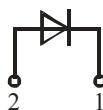


Figure 4 – Connection circuit M4.1

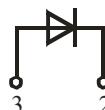


Figure 5 – Connection circuit M4.1A

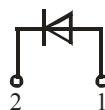


Figure 6 – Connection circuit M4.1B

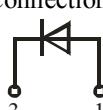


Figure 7 – Connection circuit M4.1C

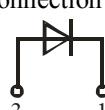


Figure 8 – Connection circuit M4.1G

## BASIC CHARACTERISTICS

$T = 25^{\circ}\text{C}$

Product name	Pulse direct voltage, $U_{\text{FM}}$ , V		Repetitive pulse reverse current, $I_{\text{RRM}}$ , mA		Electric isolation strength at DC between radiator and power outputs, $U_{\text{ISOL}}$ , V		Thermal junction to cooler resistance, $R_{\text{th(j-c)}}$ , ( $^{\circ}\text{C/W}$ )	
	max	$I_{\text{O}}$ , A amplit. value	max	$U_{\text{O}}$ , V	min	t, minute		
M4.1x-25-12	1.65	$\pi \cdot I_{\text{F(AV)}}$ , 10 ms, 50 Hz, sinus	1.0	1200	4000	1	0.8	
M4.1x-40-12							0.7	
M4.1x-63-12							0.55	
M4.1x-80-12							0.45	
M4.1x-100-12							0.3	
M4.1x-125-12							0.25	
M4.1x-160-12							0.22	
M4.1x-200-12							0.19	
M4.1x-250-12							0.15	

## MAXIMUM ALLOWABLE OPERATING MODES

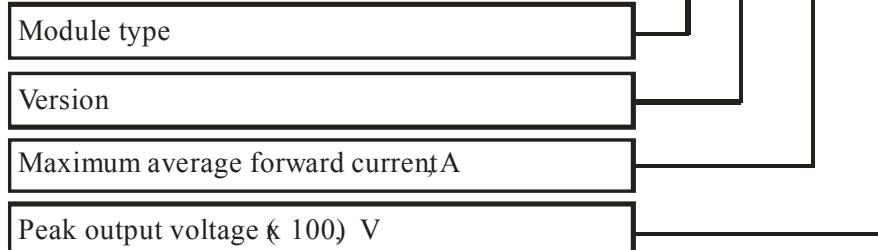
Product name	Non-repetitive pulse reverse voltage $U_{\text{RSM}}$ , V	Diode repeti- tive pulse reverse vol- tage/ in off- state, $U_{\text{RRM}}$ , V	Diode average DC $I_{\text{F(AV)}}$ , A	Diode root- mean-square DC $I_{\text{FRMS}}$ , A	Diode surge DC $I_{\text{F(SM)}}$ , A	Critical rate of rise of on-state current, $(di_T / dt)$ cr, A/ $\mu\text{s}$	Junction temperature, $T_{\text{VJ}}^{**}$ , °C		
			max	max	max				
M4.1x-25-12	1300	1200	25	39	200	10	150	- 40	+125
M4.1x-40-12			40	63	560				
M4.1x-63-12			63	95	720				
M4.1x-80-12			80	125	960				
M4.1x-100-12			100	155	1350				
M4.1x-125-12			125	188	2500				
M4.1x-160-12			160	250	4000				
M4.1x-200-12			200	310	5000				
M4.1x-250-12			250	390	6000				

\* the modules are designed to operate in equipment with using of coolers that support transition temperature in the prescribed ranges

Precious metals are not contained

## MODULE DESCRIPTION

M4.1 A - 63 - 12



Note – when ordering the module, you must specify the housing type (E1, E2, DM)

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